2SC4264

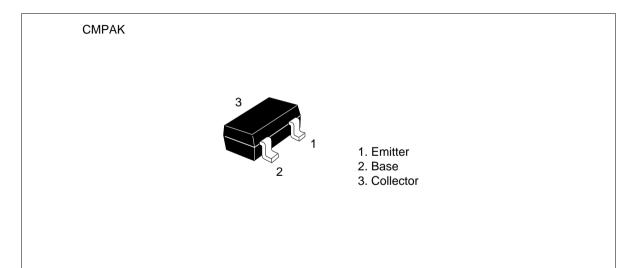
Silicon NPN Epitaxial

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Application

VHF / UHF RF amplifier, Local oscillator, Mixer

Outline





2SC4264

Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

Item	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	20	V
Collector to emitter voltage	V _{CEO}	11	V
Emitter to base voltage	V _{EBO}	3	V
Collector current	Ι _c	50	mA
Collector power dissipation	Pc	100	mW
Junction temperature	Тј	150	°C
Storage temperature	Tstg	-55 to +150	°C

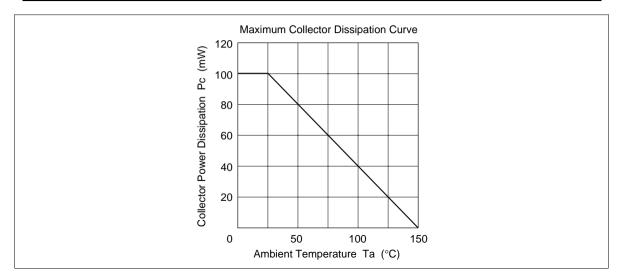
Electrical Characteristics ($Ta = 25^{\circ}C$)

Item	Symbol	Min	Тур	Мах	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	20	_	_	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector cutoff current	I _{CBO}	_	_	0.5	μΑ	$V_{CB} = 15 \text{ V}, I_{E} = 0$
	I _{CEO}	—	_	10	μA	V_{CE} = 11 V, R_{BE} = ∞
Emitter cutoff current	I _{EBO}	—	_	1.0	μA	$V_{EB} = 3 V, I_{C} = 0$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	—	_	0.7	V	$I_{c} = 10 \text{ mA}, I_{B} = 5 \text{ mA}$
DC current transfer ratio	h _{FE}	20	_	_		$V_{ce} = 10 \text{ V}, I_c = 5 \text{ mA}$
Collector output capacitance	Cob	_	_	1.5	pF	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{MHz}$
Gain bandwidth product	f _T	1.4	_		GHz	$V_{ce} = 10 \text{ V}, I_c = 10 \text{ mA}$
Natar Marking is #000						

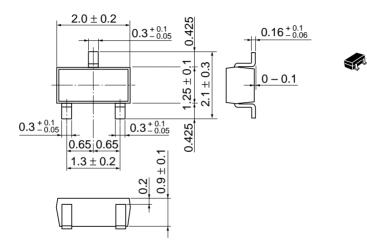
Note: Marking is "GC".

See characteristic curves of 2SC2734.

2SC4264



Unit: mm



Hitachi Code	CMPAK
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.006 g

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